Unit: mm

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

HN1K05FU

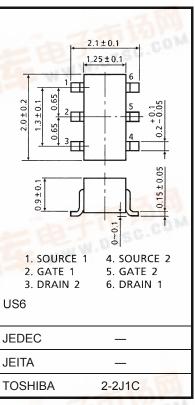
For Portable Devices

High Speed Switching Applications
Interface Applications

- High input impedance and extremely low drive current.
- V_{th} is low and it is possible to drive directly at low-voltage CMOS. : $V_{th} = 0.5$ to 1.0 V
- Suitable for high-density mounting because of a compact package.

Absolute Maximum Ratings (Ta = 25°C) (Q1, Q2 common)

| Characteristics | Symbol | Rating | Unit | |
|---------------------------|-------------------------|------------|------|--|
| Drain-source voltage | V _{DS} | 20 | V | |
| Gate-source voltage | V _{GSS} | 10 | V | |
| DC drain current | ID | 100 | mA | |
| Drain power dissipation | P _D (Note 1) | 200 | mW | |
| Channel temperature | T _{ch} | 150 | °C | |
| Storage temperature range | T _{stg} | -55 to 150 | °C | |



Weight: 6.8 mg

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

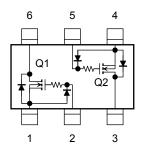
Note 1: TOTAL rating



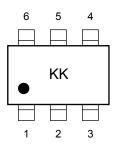
Electrical Characteristics (Ta = 25°C) (Q1, Q2 common)

| Characteristic | Symbol | Test Condition | Min | Тур. | Max | Unit |
|--------------------------------|------------------------|---|-----|------|-----|------|
| Gate leakage current | I _{GSS} | V _{GS} = 10 V, V _{DS} = 0 V | _ | _ | 1 | μА |
| Drain-source breakdown voltage | V (BR) DSS | $I_D = 100 \mu A, V_{GS} = 0 V$ | 20 | _ | _ | V |
| Drain cut-off current | I _{DSS} | V _{DS} = 20 V, V _{GS} = 0 V | _ | _ | 1 | μА |
| Gate threshold voltage | V_{th} | $V_{DS} = 1.5 \text{ V}, I_D = 0.1 \text{ mA}$ | 0.5 | _ | 1 | V |
| Forward transfer admittance | Y _{fs} | $V_{DS} = 1.5 \text{ V}, I_D = 10 \text{ mA}$ | 35 | 70 | _ | mS |
| Drain-Source ON resistance 1 | R _{DS} (ON) 1 | $I_D = 1 \text{ mA}, V_{GS} = 1.2 \text{ V}$ | _ | 15 | 50 | Ω |
| Drain-Source ON resistance 2 | R _{DS} (ON) 2 | $I_D = 10 \text{ mA}, V_{GS} = 1.5 \text{ V}$ | _ | 10 | 40 | Ω |
| Drain-Source ON resistance 3 | R _{DS} (ON) 3 | $I_D = 10 \text{ mA}, V_{GS} = 2.5 \text{ V}$ | _ | 7 | 28 | Ω |
| Input capacitance | C _{iss} | V _{DS} = 1.5 V, V _{GS} = 0 V, f = 1 MHz | _ | 12 | _ | pF |
| Reverse transfer capacitance | C _{rss} | V _{DS} = 1.5 V, V _{GS} = 0 V, f = 1 MHz | _ | 3.4 | _ | pF |
| Output capacitance | Coss | V _{DS} = 1.5 V, V _{GS} = 0 V, f = 1 MHz | _ | 12 | _ | pF |
| Switching time | t _{on} | $V_{DD} = 1.5 \text{ V}, I_D = 10 \text{ mA}, V_{GS} = 0 \text{ to } 1.5 \text{ V}$ | _ | 0.35 | _ | 6 |
| | t _{off} | $V_{DD} = 1.5 \text{ V}, I_D = 10 \text{ mA}, V_{GS} = 0 \text{ to } 1.5 \text{ V}$ | _ | 0.2 | _ | μS |

Equivalent Circuit (top view)



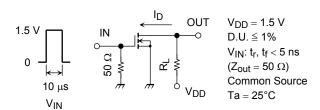
Marking



(Q1, Q2 common)

Switching Time Test Circuit

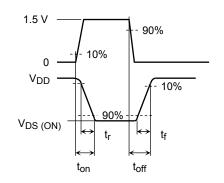
(a) Test circuit



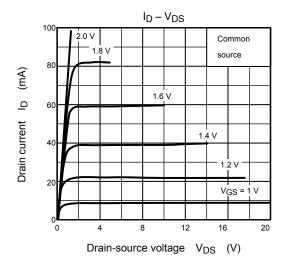
(b) V_{IN}

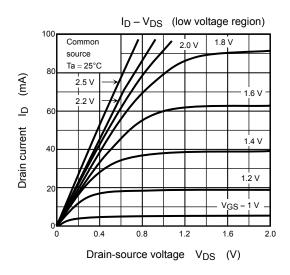
 $V_{\rm GS}$

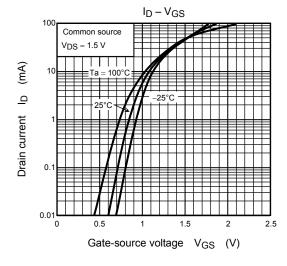


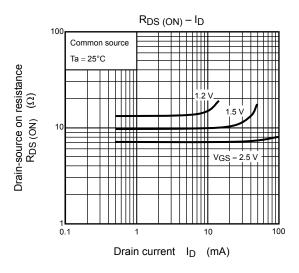


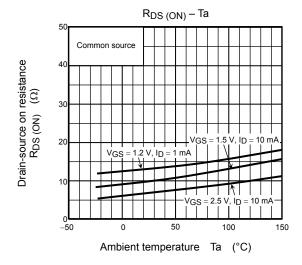
(Q1, Q2 common)

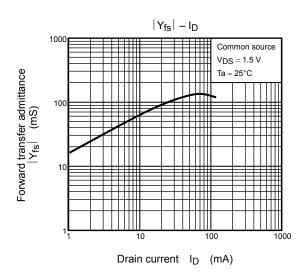




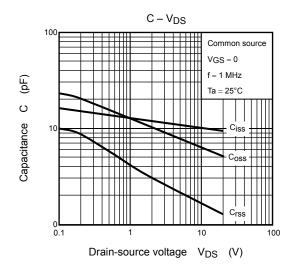


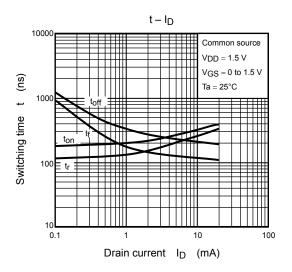


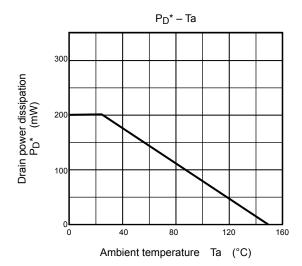




(Q1, Q2 common)







*: TOTAL rating

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20070701-EN GENERAL

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